

FEATURES

- Low Reverse Recovery Charge
- High Switching Speed
- Low Forward Volt Drop
- Isolated AISiC Base with AlN Substrates
- Dual Diodes can be paralleled for 1000A Rating
- Lead Free Construction
- 10.2kV Isolation Package

APPLICATIONS

- Brake Chopper Diodes
- Boost and Buck Circuits
- Free-wheel Circuits
- Motor Drives
- Resonant Converters
- Induction Heating
- Multi-level Switch Inverters

The DFM500XXM65-TS000 is a dual 6500V, fast recovery diode (FRD) module. Designed for low power loss, the module is suitable for a variety of high voltage applications in motor drives and power conversion.

Fast switching times and low reverse recovery losses allow high frequency operation, making the device suitable for the latest drive designs employing PWM and high frequency switching.

The module incorporates an electrically isolated base plate and low inductance construction enabling circuit designers to optimise circuit layouts and utilise grounded heat sinks for safety.

ORDERING INFORMATION

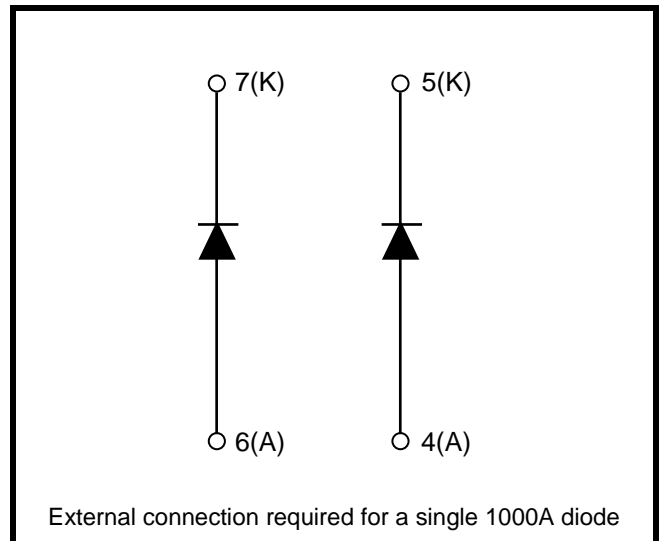
Order As:

DFM500XXM65-TS000

Note: When ordering, please use the complete part number

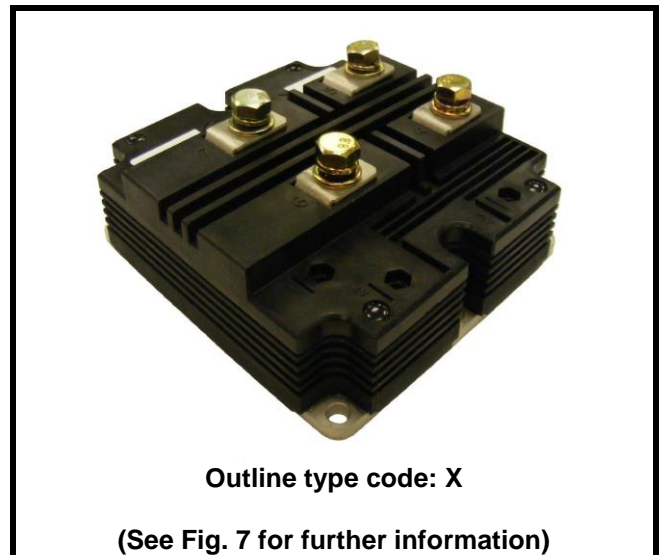
KEY PARAMETERS

V_{RRM}		6500V
V_F	(typ)	3.6V
I_F	(max)	500A
I_{FM}	(max)	1000A



External connection required for a single 1000A diode

Fig. 1 Circuit configuration



Outline type code: X

(See Fig. 7 for further information)

Fig. 2 Package

ABSOLUTE MAXIMUM RATINGS

Stresses above those listed under ‘Absolute Maximum Ratings’ may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

T_{case} = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
V _{RRM}	Repetitive peak reverse voltage	T _j = 125°C	6500	V
		T _j = 25°C	6500	V
		T _j = -40°C	6000	V
I _F	Forward current (per arm)	DC, T _{case} = 70°C, T _j = 125°C	500	A
I _{FM}	Max. forward current	T _{case} = 115°C, t _p = 1ms	1000	A
I ² t	I ² t value fuse current rating	V _R = 0, t _p = 10ms, T _j = 125°C	90	kA ² s
P _{max}	Max. power dissipation	T _{case} = 25°C, T _j = 125°C	3300	W
V _{isol}	Isolation voltage – per module	Commoned terminals to base plate. AC RMS, 1 min, 50Hz	10.2	kV
Q _{PD}	Partial discharge – per module	IEC1287, V ₁ = 6900V, V ₂ = 5100V, 50Hz RMS	10	pC

THERMAL AND MECHANICAL RATINGS

Internal insulation material:	AlN
Baseplate material:	AlSiC
Creepage distance:	56mm
Clearance:	26mm
CTI (Comparative Tracking Index):	> 600

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Units
R _{th(j-c)}	Thermal resistance (per arm)	Continuous dissipation – junction to case	-	-	30	°C/kW
R _{th(c-h)}	Thermal resistance – case to heatsink (per module)	Mounting torque 5Nm (with mounting grease)	-	-	8	°C/kW
T _j	Junction temperature		-40	-	150	°C
T _{stg}	Storage temperature range		-40	-	150	°C
	Screw Torque	Mounting – M6	-	-	5	Nm
		Electrical connections – M8	-	-	10	Nm

STATIC ELECTRICAL CHARACTERISTICS – PER ARM

$T_{case} = 25^{\circ}\text{C}$ unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
I_{RM}	Peak reverse current	$V_R = 6500\text{V}, T_j = 125^{\circ}\text{C}$			33	mA
V_F	Forward voltage	$I_F = 500\text{A}$		3.6		V
		$I_F = 500\text{A}, T_j = 125^{\circ}\text{C}$		4.3		V
L_M	Inductance	-		40		nH

STATIC ELECTRICAL CHARACTERISTICS

$T_{case} = 25^{\circ}\text{C}$ unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
L_M	Module inductance (externally connected in parallel)	-		20		nH
R_{INT}	Internal resistance (per arm)	-		370		$\mu\Omega$

DYNAMIC ELECTRICAL CHARACTERISTICS – PER ARM

$T_{case} = 25^{\circ}\text{C}$ unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Units
Q_{rr}	Reverse recovery charge	$I_F = 500\text{A}$ $V_R = 3600\text{V}$ $di_F/dt = 1300\text{A}/\mu\text{s}$		900		μC
I_{rr}	Peak reverse recovery current			550		A
E_{rec}	Reverse recovery energy			2000		mJ

$T_{case} = 125^{\circ}\text{C}$ unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Units
Q_{rr}	Reverse recovery charge	$I_F = 500\text{A}$ $V_R = 3600\text{V}$ $di_F/dt = 1300\text{A}/\mu\text{s}$		1400		μC
I_{rr}	Peak reverse recovery current			650		A
E_{rec}	Reverse recovery energy			3200		mJ

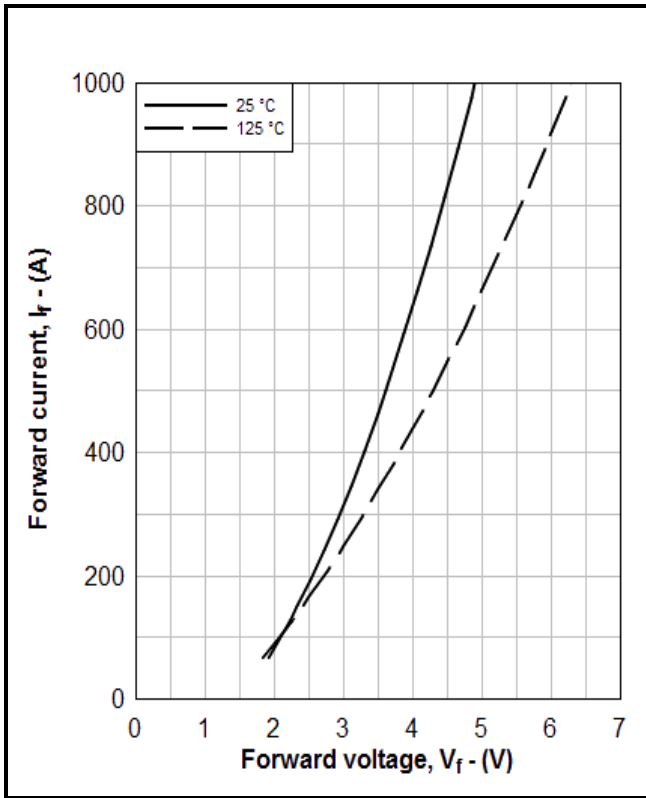


Fig. 3 Diode typical forward characteristics

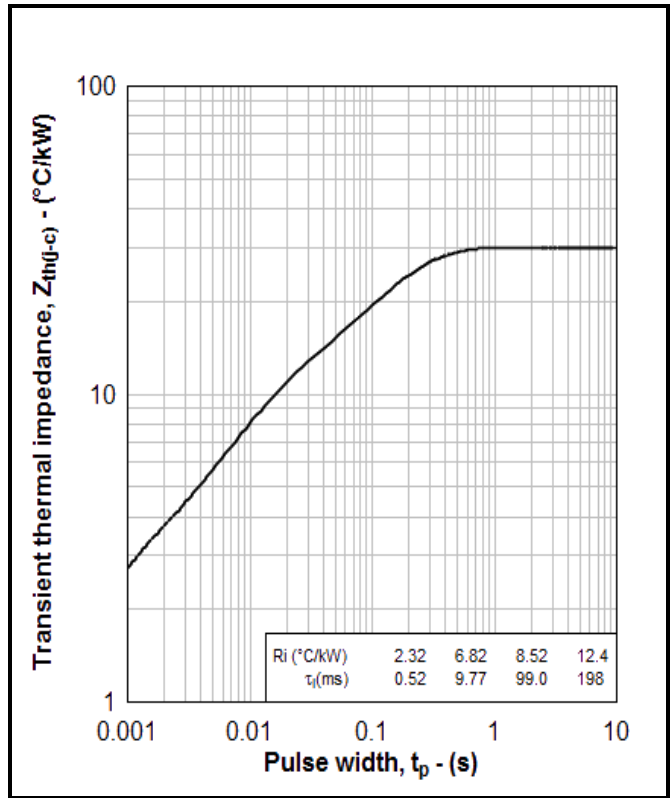


Fig. 4 Transient thermal impedance

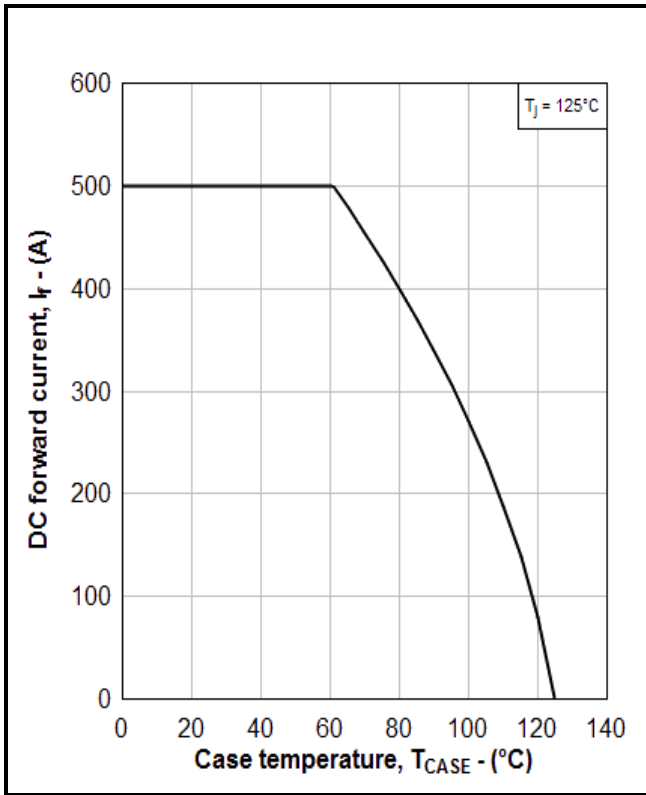


Fig. 5 DC current rating vs case temperature

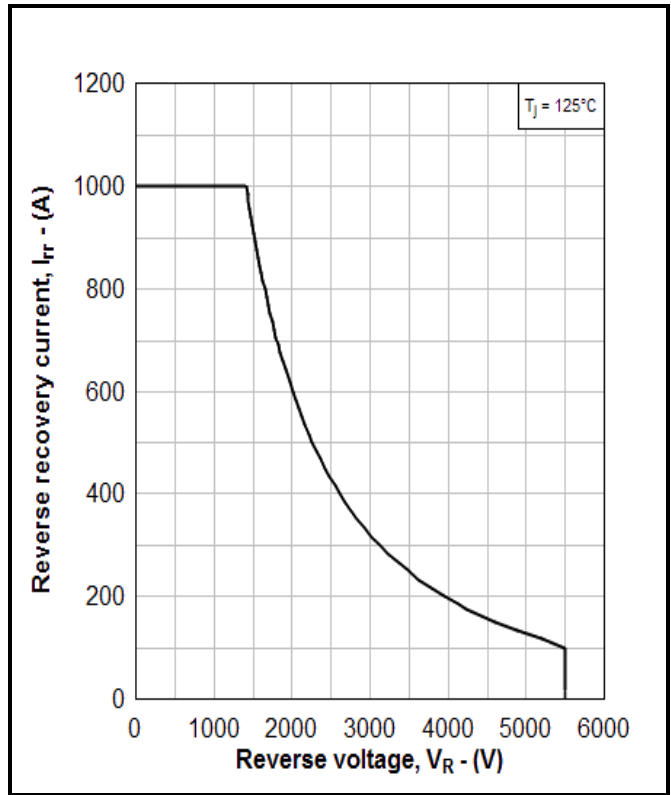
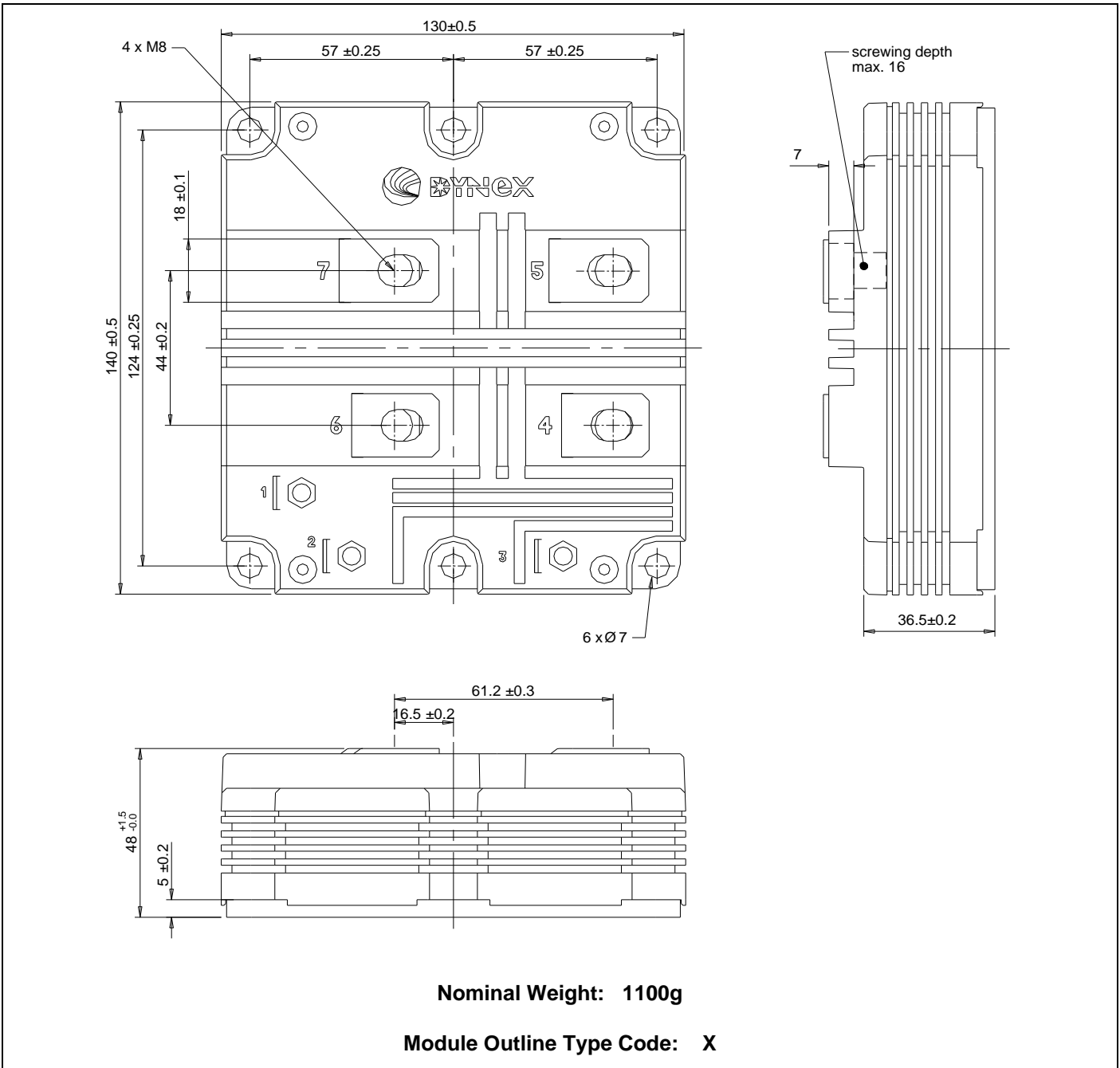


Fig. 6 Reverse Bias Safe Operating Area (RBSOA)

PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services.
All dimensions in mm, unless stated otherwise.
DO NOT SCALE.



Nominal Weight: 1100g

Module Outline Type Code: X

Fig. 7 Module outline drawing

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